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Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Obsolete
Core Processor	ARM7TDMI
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	74MHz
Co-Processors/DSP	-
RAM Controllers	SDRAM
Graphics Acceleration	No
Display & Interface Controllers	Keypad, LCD, Touchscreen
Ethernet	-
SATA	-
USB	-
Voltage - I/O	2.5V, 2.7V, 3.0V, 3.3V
Operating Temperature	-40°C ~ 85°C (TA)
Security Features	Hardware ID
Package / Case	208-LQFP
Supplier Device Package	208-LQFP
Purchase URL	https://www.e-xfl.com/product-detail/cirrus-logic/ep7311-iv

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The second is the programmable 16- or 32-bit-wide SDRAM interface that allows direct connection of up to two banks of SDRAM, totaling 512 Mb. To assure the lowest possible power consumption, the EP7311 supports self-refresh SDRAMs, which are placed in a low-power state by the device when it enters the low-power Standby State.

Pin Mnemonic	I/O	Pin Description
SDCLK	O	SDRAM clock output
SDCKE	O	SDRAM clock enable output
nSDCS[1:0]	O	SDRAM chip select out
WRITE/nSDRAS (Note 2)	O	SDRAM RAS signal output
nMOE/nSDCAS (Note 2)	O	SDRAM CAS control signal
nMWE/nSDWE (Note 2)	O	SDRAM write enable control signal
A[27:15]/DRA[0:12] (Note 1)	O	SDRAM address
A[14:13]/DRA[12:14]	O	SDRAM internal bank select
PD[7:6]/SDQM[1:0] (Note 2)	I/O	SDRAM byte lane mask
SDQM[3:2]	O	SDRAM byte lane mask
D[31:0]	I/O	Data I/O

Table C. SDRAM Interface Pin Assignments

Note: 1. Pins A[27:13] map to DRA[0:14] respectively.
(i.e. A[27]/DRA[0], A[26]/DRA[1], etc.) This is to balance the load for large memory systems.
2. Pins are multiplexed. See [Table S on page 11](#) for more information.

Digital Audio Capability

The EP7311 uses its powerful 32-bit RISC processing engine to implement audio decompression algorithms in software. The nature of the on-board RISC processor, and the availability of efficient C-compilers and other software development tools, ensures that a wide range of audio decompression algorithms can easily be ported to and run on the EP7311

Universal Asynchronous Receiver/Transmitters (UARTs)

The EP7311 includes two 16550-type UARTs for RS-232 serial communications, both of which have two 16-byte FIFOs for receiving and transmitting data. The UARTs support bit rates up to 115.2 kbps. An IrDA SIR protocol encoder/decoder can be optionally switched into the RX/TX signals to/from

UART 1 to enable these signals to drive an infrared communication interface directly.

Pin Mnemonic	I/O	Pin Description
TXD[1]	O	UART 1 transmit
RXD[1]	I	UART 1 receive
CTS	I	UART 1 clear to send
DCD	I	UART 1 data carrier detect
DSR	I	UART 1 data set ready
TXD[2]	O	UART 2 transmit
RXD[2]	I	UART 2 receive
LEDDRV	O	Infrared LED drive output
PHDIN	I	Photo diode input

Table D. Universal Asynchronous Receiver/Transmitters Pin Assignments

Multimedia Codec Port (MCP)

The Multimedia Codec Port provides access to an audio codec, a telecom codec, a touchscreen interface, four general purpose analog-to-digital converter inputs, and ten programmable digital I/O lines.

Pin Mnemonic	I/O	Pin Description
SIBCLK	O	Serial bit clock
SIBDOUT	O	Serial data out
SIBDIN	I	Serial data in
SIBSYNC	O	Sample clock

Table E. MCP Interface Pin Assignments

Note: See [Table R on page 11](#) for information on pin multiplexes.

CODEC Interface

The EP7311 includes an interface to telephony-type CODECs for easy integration into voice-over-IP and other voice communications systems. The CODEC interface is multiplexed to the same pins as the MCP and SSI2.

Pin Mnemonic	I/O	Pin Description
PCMCLK	O	Serial bit clock
PCMOUT	O	Serial data out
PCMIN	I	Serial data in
PCMSYNC	O	Frame sync

Table F. CODEC Interface Pin Assignments

Note: See [Table R on page 11](#) for information on pin multiplexes.

SSI2 Interface

An additional SPI/Microwire1-compatible interface is available for both master and slave mode communications. The SSI2 unit shares the same pins as the MCP and CODEC interfaces through a multiplexer.

- Synchronous clock speeds of up to 512 kHz
- Separate 16 entry TX and RX half-word wide FIFOs
- Half empty/full interrupts for FIFOs
- Separate RX and TX frame sync signals for asymmetric traffic

Pin Mnemonic	I/O	Pin Description
SSICLK	I/O	Serial bit clock
SSITXDA	O	Serial data out
SSIRXDA	I	Serial data in
SSITXFR	I/O	Transmit frame sync
SSIRXFR	I/O	Receive frame sync

Table G. SSI2 Interface Pin Assignments

Note: See [Table R on page 11](#) for information on pin multiplexes.

Synchronous Serial Interface

- ADC (SSI) Interface: Master mode only; SPI and Microwire1-compatible (128 kbps operation)
- Selectable serial clock polarity

Pin Mnemonic	I/O	Pin Description
ADCLK	O	SSI1 ADC serial clock
ADCIN	I	SSI1 ADC serial input
ADCOUT	O	SSI1 ADC serial output
nADCCS	O	SSI1 ADC chip select
SMPCLK	O	SSI1 ADC sample clock

Table H. Serial Interface Pin Assignments

LCD Controller

A DMA address generator is provided that fetches video display data for the LCD controller from memory. The display frame buffer start address is programmable, allowing the LCD frame buffer to be in SDRAM, internal SRAM or external SRAM.

- Interfaces directly to a single-scan panel monochrome STN LCD
- Interfaces to a single-scan panel color STN LCD with minimal external glue logic
- Panel width size is programmable from 32 to 1024 pixels in 16-pixel increments
- Video frame buffer size programmable up to 128 KB
- Bits per pixel of 1, 2, or 4 bits

Pin Mnemonic	I/O	Pin Description
CL1	O	LCD line clock
CL2	O	LCD pixel clock out
DD[3:0]	O	LCD serial display data bus
FRM	O	LCD frame synchronization pulse
M	O	LCD AC bias drive

Table I. LCD Interface Pin Assignments

64-Keypad Interface

Matrix keyboards and keypads can be easily read by the EP7311. A dedicated 8-bit column driver output generates strobes for each keyboard column signal. The pins of Port A, when configured as inputs, can be selectively OR'ed together to provide a keyboard interrupt that is capable of waking the system from a STANDBY or IDLE state.

- Column outputs can be individually set high with the remaining bits left at high-impedance
- Column outputs can be driven all-low, all-high, or all-high-impedance
- Keyboard interrupt driven by OR'ing together all Port A bits
- Keyboard interrupt can be used to wake up the system
- 8×8 keyboard matrix usable with no external logic, extra keys can be added with minimal glue logic

Pin Mnemonic	I/O	Pin Description
COL[7:0]	O	Keyboard scanner column drive

Table J. Keypad Interface Pin Assignments

Interrupt Controller

When unexpected events arise during the execution of a program (i.e., interrupt or memory fault) an exception is usually generated. When these exceptions occur at the same time, a fixed priority system determines the order in which they are handled. The EP7311 interrupt controller has two interrupt types: interrupt request (IRQ) and fast interrupt request (FIQ). The interrupt controller has the ability to control interrupts from 22 different FIQ and IRQ sources.

- Supports 22 interrupts from a variety of sources (such as UARTs, SSI1, and key matrix.)
- Routes interrupt sources to the ARM720T's IRQ or FIQ (Fast IRQ) inputs
- Five dedicated off-chip interrupt lines operate as level sensitive interrupts

Pin Mnemonic	I/O	Pin Description
nEINT[2:1]	I	External interrupt
EINT[3]	I	External interrupt
nEXTFIQ	I	External Fast Interrupt input
nMEDCHG/nBROM (Note)	I	Media change interrupt input

Table K. Interrupt Controller Pin Assignments

Note: Pins are multiplexed. See [Table S on page 11](#) for more information.

Real-Time Clock

The EP7311 contains a 32-bit Real Time Clock (RTC) that can be written to and read from in the same manner as the timer counters. It also contains a 32-bit output match register which can be programmed to generate an interrupt.

- Driven by an external 32.768 kHz crystal oscillator

Pin Mnemonic	Pin Description
RTCCIN	Real-Time Clock Oscillator Input
RTCCOUT	Real-Time Clock Oscillator Output
VDDRTC	Real-Time Clock Oscillator Power
VSSRTC	Real-Time Clock Oscillator Ground

Table L. Real-Time Clock Pin Assignments

PLL and Clocking

- Processor and Peripheral Clocks operate from a single 3.6864 MHz crystal or external 13 MHz clock
- Programmable clock speeds allow the peripheral bus to run at 18 MHz when the processor is set to 18 MHz and at 36 MHz when the processor is set to 36, 49 or 74 MHz

Pin Mnemonic	Pin Description
MOSCIN	Main Oscillator Input
MOSCOUT	Main Oscillator Output
VDDOSC	Main Oscillator Power
VSSOSC	Main Oscillator Ground

Table M. PLL and Clocking Pin Assignments

DC-to-DC converter interface (PWM)

- Provides two 96 kHz clock outputs with programmable duty ratio (from 1-in-16 to 15-in-16) that can be used to drive a positive or negative DC to DC converter

Pin Mnemonic	I/O	Pin Description
DRIVE[1:0]	I/O	PWM drive output
FB[1:0]	I	PWM feedback input

Table N. DC-to-DC Converter Interface Pin Assignments

Timers

- Internal (RTC) timer
- Two internal 16-bit programmable hardware count-down timers

General Purpose Input/Output (GPIO)

- Three 8-bit and one 3-bit GPIO ports
- Supports scanning keyboard matrix

Pin Mnemonic	I/O	Pin Description
PA[7:0]	I/O	GPIO port A
PB[7:0]	I/O	GPIO port B
PD[0]/LEDFLSH (Note)	I/O	GPIO port D
PD[5:1]	I/O	GPIO port D
PD[7:6]/SDQM[1:0] (Note)	I/O	GPIO port D
PE[1:0]/BOOTSEL[1:0] (Note)	I/O	GPIO port E
PE[2]/CLKSEL (Note)	I/O	GPIO port E

Table O. General Purpose Input/Output Pin Assignments

Note: Pins are multiplexed. See [Table S on page 11](#) for more information.

Hardware debug Interface

- Full JTAG boundary scan and Embedded ICE® support

Pin Mnemonic	I/O	Pin Description
TCLK	I	JTAG clock
TDI	I	JTAG data input
TDO	O	JTAG data output
nTRST	I	JTAG async reset input
TMS	I	JTAG mode select

Table P. Hardware Debug Interface Pin Assignments

LED Flasher

A dedicated LED flasher module can be used to generate a low frequency signal on Port D pin 0 for the purpose of blinking an LED without CPU intervention. The LED flasher feature is ideal as a visual annunciator in battery powered applications, such as a voice mail indicator on a portable phone or an appointment reminder on a PDA.

- Software adjustable flash period and duty cycle
- Operates from 32 kHz RTC clock
- Will continue to flash in IDLE and STANDBY states
- 4 mA drive current

Pin Mnemonic	I/O	Pin Description
PD[0]/LEDFLSH (Note)	O	LED flasher driver

Table Q. LED Flasher Pin Assignments

Note: Pins are multiplexed. See [Table S on page 11](#) for more information.

Internal Boot ROM

The internal 128 byte Boot ROM facilitates download of saved code to the on-board SRAM/FLASH.

Packaging

The EP7311 is available in a 208-pin LQFP package, 256-ball PBGA package or a 204-ball TFBGA package.

System Design

As shown in system block diagram, simply adding desired memory and peripherals to the highly integrated EP7311

completes a low-power system solution. All necessary interface logic is integrated on-chip.

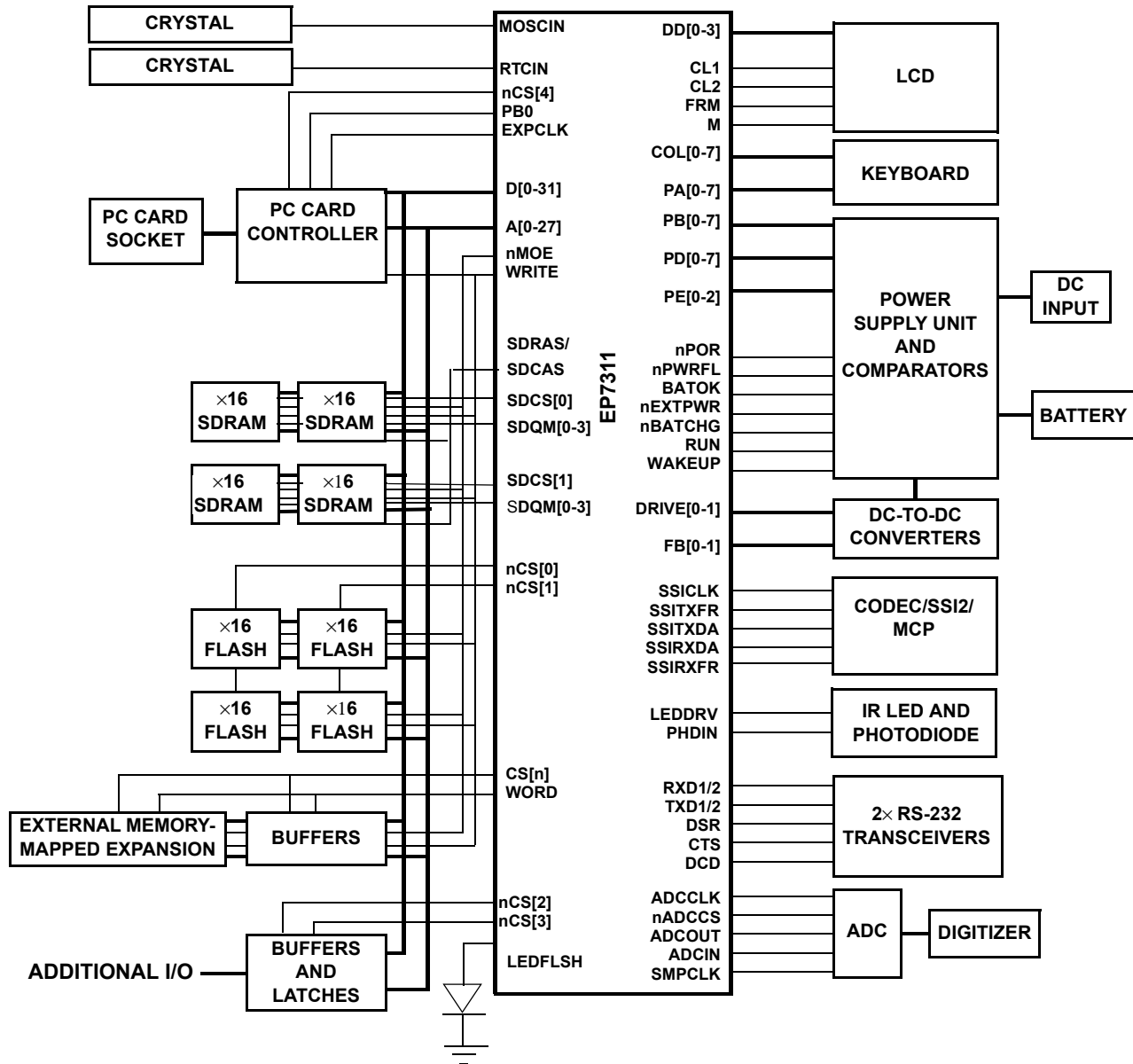


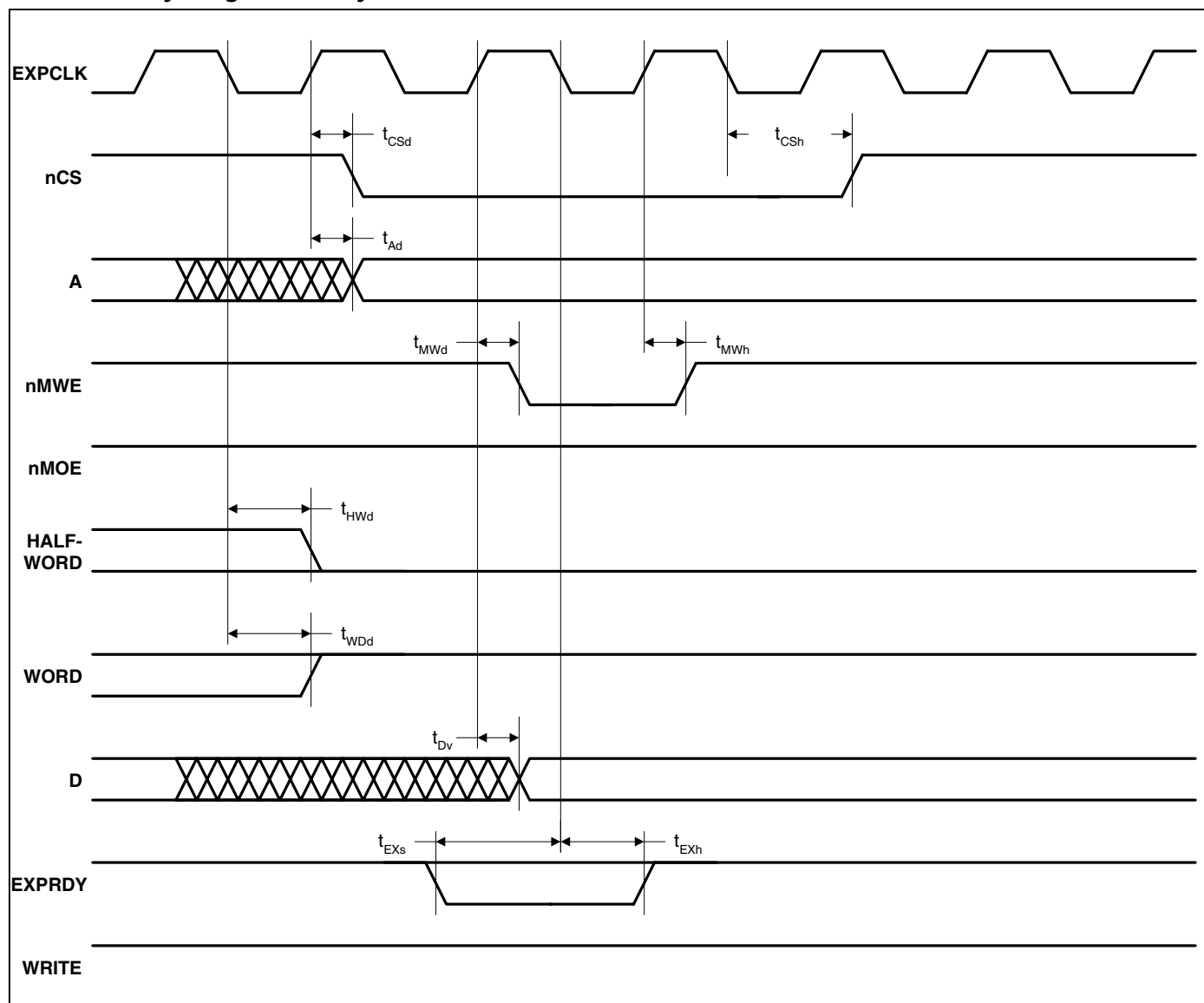
Figure 1. A Maximum EP7311 Based System

Note: A system can only use one of the following peripheral interfaces at any given time: SSI2, CODEC or MCP.

Static Memory

Figure 7 through Figure 10 define the timings associated with all phases of the Static Memory. The following table contains the values for the timings of each of the Static Memory modes.

Parameter	Symbol	Min	Typ	Max	Unit
EXPCLK rising edge to nCS assert delay time	t_{CSd}	2	8	20	ns
EXPCLK falling edge to nCS deassert hold time	t_{CSh}	2	7	20	ns
EXPCLK rising edge to A assert delay time	t_{Ad}	4	9	16	ns
EXPCLK falling edge to A deassert hold time	t_{Ah}	3	10	19	ns
EXPCLK rising edge to nMWE assert delay time	t_{MWd}	3	6	10	ns
EXPCLK rising edge to nMWE deassert hold time	t_{MWh}	3	6	10	ns
EXPCLK falling edge to nMOE assert delay time	t_{MOEd}	3	7	10	ns
EXPCLK falling edge to nMOE deassert hold time	t_{MOEh}	2	7	10	ns
EXPCLK falling edge to HALFWORD deassert delay time	t_{HWd}	2	8	20	ns
EXPCLK falling edge to WORD assert delay time	t_{WDd}	2	8	16	ns
EXPCLK rising edge to data valid delay time	t_{Dv}	8	13	21	ns
EXPCLK falling edge to data invalid delay time	t_{Dnv}	6	15	30	ns
Data setup to EXPCLK falling edge time	t_{Ds}	-	-	1	ns
EXPCLK falling edge to data hold time	t_{Dh}	-	-	3	ns
EXPCLK rising edge to WRITE assert delay time	t_{WRd}	5	11	23	ns
EXPREADY setup to EXPCLK falling edge time	t_{EXs}	-	-	0	ns
EXPCLK falling edge to EXPREADY hold time	t_{EXh}	-	-	0	ns

Static Memory Single Write Cycle

Figure 8. Static Memory Single Write Cycle Timing Measurement

- Note:**
1. The cycle time can be extended by integer multiples of the clock period (22 ns at 45 MHz, 27 ns at 36 MHz, 54 ns at 18.432 MHz, and 77 ns at 13 MHz), by either driving EXPRDY low and/or by programming a number of wait states. EXPRDY is sampled on the falling edge of EXPCLK before the data transfer. If low at this point, the transfer is delayed by one clock period where EXPRDY is sampled again. EXPCLK need not be referenced when driving EXPRDY, but is shown for clarity.
 2. Zero wait states for sequential writes is not permitted for memory devices which use nMWE pin, as this cannot be driven with valid timing under zero wait state conditions.
 3. Address, Data, Halfword, Word, and Write hold state until next cycle.

Static Memory Burst Write Cycle

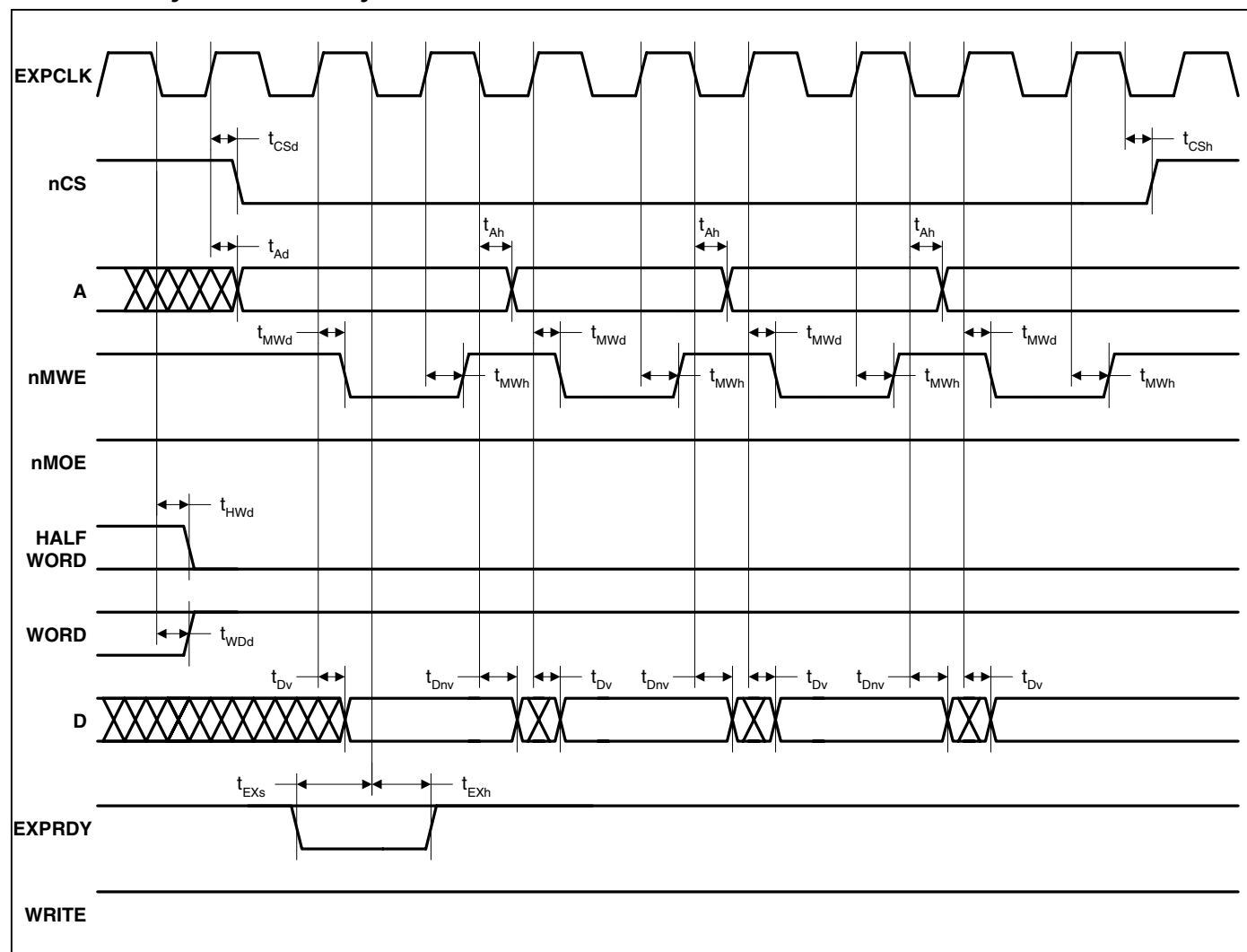


Figure 10. Static Memory Burst Write Cycle Timing Measurement

- Note:**
1. Four cycles are shown in the above diagram (minimum wait states, 1-1-1-1). This is the maximum number of consecutive cycles that can be driven. The number of consecutive cycles can be programmed from 2 to 4, inclusively.
 2. The cycle time can be extended by integer multiples of the clock period (22 ns at 45 MHz, 27 ns at 36 MHz, 54 ns at 18.432 MHz, and 77 ns at 13 MHz), by either driving EXPRDY low and/or by programming a number of wait states. EXPRDY is sampled on the falling edge of EXPCLK before the data transfer. If low at this point, the transfer is delayed by one clock period where EXPRDY is sampled again. EXPCLK need not be referenced when driving EXPRDY, but is shown for clarity.
 3. Zero wait states for sequential writes is not permitted for memory devices which use nMWE pin, as this cannot be driven with valid timing under zero wait state conditions.
 4. Address, Data, Halfword, Word, and Write hold state until next cycle.

SSI2 Interface

Parameter	Symbol	Min	Max	Unit
SSICLK period (slave mode)	$t_{\text{clk_per}}$	185	2050	ns
SSICLK high time	$t_{\text{clk_high}}$	925	1025	ns
SSICLK low time	$t_{\text{clk_low}}$	925	1025	ns
SSICLK rise/fall time	t_{clkrf}	3	18	ns
SSICLK rising edge to RX and/or TX frame sync high time	t_{FRd}	-	3	ns
SSICLK rising edge to RX and/or TX frame sync low time	t_{FRa}	-	8	ns
SSIRXFR and/or SSITXFR period	$t_{\text{FR_per}}$	960	990	ns
SSIRXDA setup to SSICLK falling edge time	t_{RXs}	3	7	ns
SSIRXDA hold from SSICLK falling edge time	t_{RXh}	3	7	ns
SSICLK rising edge to SSITXDA data valid delay time	t_{TXd}	-	2	ns
SSITXDA valid time	t_{TXv}	960	990	ns

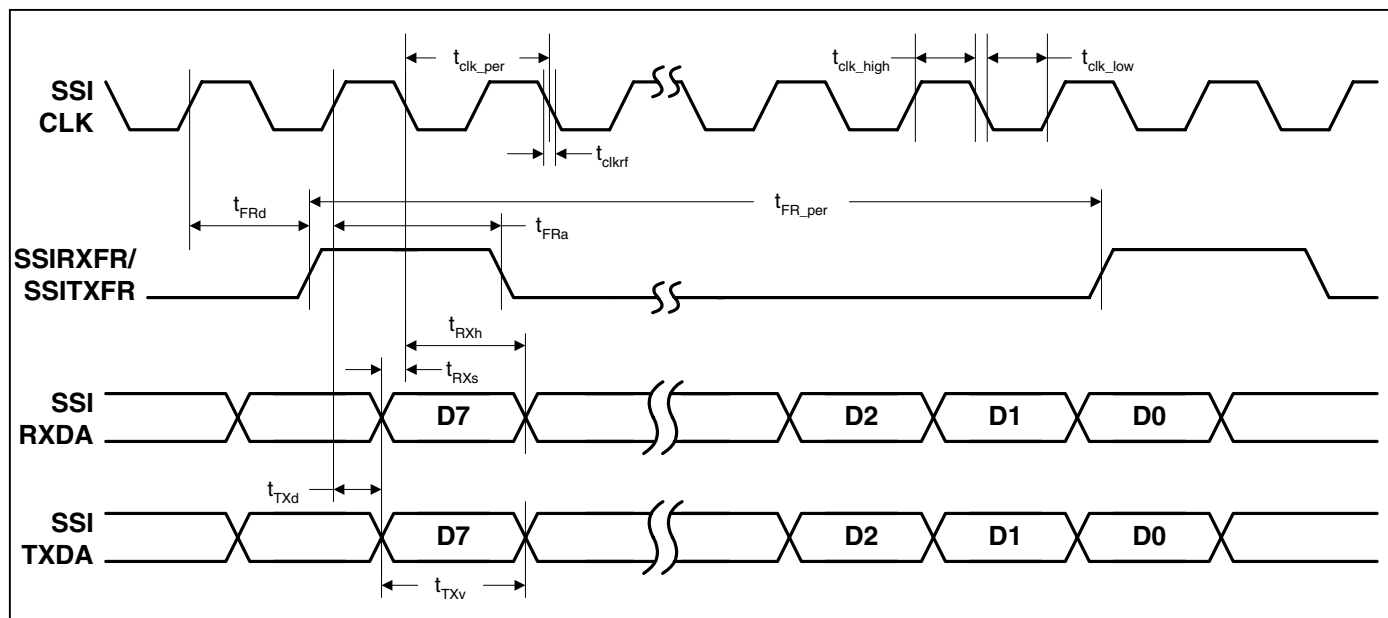


Figure 12. SSI2 Interface Timing Measurement

Packages

208-Pin LQFP Package Characteristics

208-Pin LQFP Package Specifications

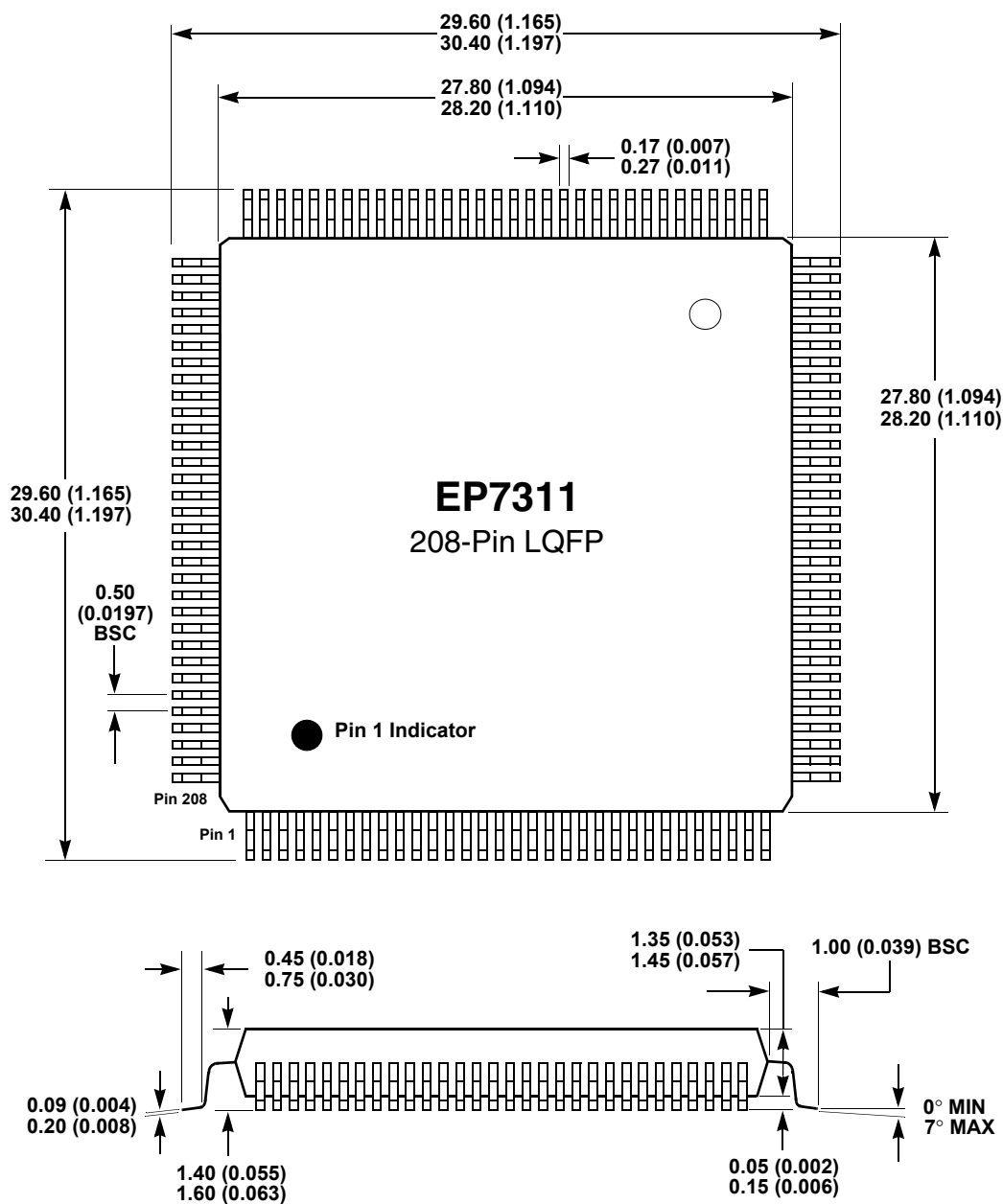


Figure 15. 208-Pin LQFP Package Outline Drawing

- Note:
- 1) Dimensions are in millimeters (inches), and controlling dimension is millimeter.
 - 2) Drawing above does not reflect exact package pin count.
 - 3) Before beginning any new design with this device, please contact Cirrus Logic for the latest package information.
 - 4) For pin locations, please see [Figure 16](#). For pin descriptions see the EP7311 User's Manual.

208-Pin LQFP Numeric Pin Listing

Table T. 208-Pin LQFP Numeric Pin Listing

Pin No.	Signal	Type	Strength	Reset State
1	nCS[5]	O	1	Low
2	VDDIO	Pad Pwr		
3	VSSIO	Pad Gnd		
4	EXPCLK	I/O	1	
5	WORD	Out	1	Low
6	WRITE/nSDRAS	Out	1	Low
7	RUN/CLKEN	O	1	Low
8	EXPRDY	I	1	
9	TXD[2]	O	1	High
10	RXD[2]	I		
11	TDI	I	with p/u*	
12	VSSIO	Pad Gnd		
13	PB[7]	I/O	1	Input
14	PB[6]	I/O	1	Input
15	PB[5]	I/O	1	Input
16	PB[4]	I/O	1	Input
17	PB[3]	I/O	1	Input
18	PB[2]	I/O	1	Input
19	PB[1]/PRDY2	I/O	1	Input
20	PB[0]/PRDY1	I/O	1	Input
21	VDDIO	Pad Pwr		
22	TDO	O	1	Three state
23	PA[7]	I/O	1	Input
24	PA[6]	I/O	1	Input
25	PA[5]	I/O	1	Input
26	PA[4]	I/O	1	Input
27	PA[3]	I/O	1	Input
28	PA[2]	I/O	1	Input
29	PA[1]	I/O	1	Input
30	PA[0]	I/O	1	Input
31	LEDDRV	O	1	Low
32	TXD[1]	O	1	High
33	VSSIO	Pad Gnd	1	High
34	PHDIN	I		
35	CTS	I		
36	RXD[1]	I		

Table T. 208-Pin LQFP Numeric Pin Listing (Continued)

Pin No.	Signal	Type	Strength	Reset State
37	DCD	I		
38	DSR	I		
39	nTEST[1]	I	With p/u*	
40	nTEST[0]	I	With p/u*	
41	EINT[3]	I		
42	nEINT[2]	I		
43	nEINT[1]	I		
44	nEXTFIQ	I		
45	PE[2]/CLKSEL	I/O	1	Input
46	PE[1]/BOOTSEL[1]	I/O	1	Input
47	PE[0]/BOOTSEL[0]	I/O	1	Input
48	VSSRTC	RTC Gnd		
49	RTCCOUT	O		
50	RTCCIN	I		
51	VDDRTC	RTC power		
52	N/C			
53	PD[7]/SDQM[1]	I/O	1	Low
54	PD[6]/SDQM[0]	I/O	1	Low
55	PD[5]	I/O	1	Low
56	PD[4]	I/O	1	Low
57	VDDIO	Pad Pwr		
58	TMS	I	with p/u*	
59	PD[3]	I/O	1	Low
60	PD[2]	I/O	1	Low
61	PD[1]	I/O	1	Low
62	PD[0]/LEDFLSH	I/O	1	Low
63	SSICLK	I/O	1	Input
64	VSSIO	Pad Gnd		
65	SSITXFR	I/O	1	Low
66	SSITXDA	O	1	Low
67	SSIRXDA	I		
68	SSIRXFR	I/O		Input
69	ADCIN	I		
70	nADCCS	O	1	High
71	VSSCORE	Core Gnd		
72	VDDCORE	Core Pwr		

Table T. 208-Pin LQFP Numeric Pin Listing (Continued)

Pin No.	Signal	Type	Strength	Reset State
148	A[7]	O	1	Low
149	VSSIO	Pad Gnd		
150	D[7]	I/O	1	Low
151	nBATCHG	I		
152	nEXTPWR	I		
153	BATOK	I		
154	nPOR	I	Schmitt	
155	nMEDCHG/ nBROM	I		
156	nURESET	I	Schmitt	
157	VDDOSC	Osc Pwr		
158	MOSCIN	Osc		
159	MOSCOU	Osc		
160	VSSOSC	Osc Gnd		
161	WAKEUP	I	Schmitt	
162	nPWRFL	I		
163	A[6]	O	1	Low
164	D[6]	I/O	1	Low
165	A[5]	Out	1	Low
166	D[5]	I/O	1	Low
167	VDDIO	Pad Pwr		
168	VSSIO	Pad Gnd		
169	A[4]	O	1	Low
170	D[4]	I/O	1	Low
171	A[3]	O	2	Low
172	D[3]	I/O	1	Low
173	A[2]	O	2	Low
174	VSSIO	Pad Gnd		
175	D[2]	I/O	1	Low
176	A[1]	O	2	Low
177	D[1]	I/O	1	Low
178	A[0]	O	2	Low
179	D[0]	I/O	1	Low
180	VSS CORE	Core Gnd		
181	VDD CORE	Core Pwr		
182	VSSIO	Pad Gnd		
183	VDDIO	Pad Pwr		
184	CL[2]	O	1	Low
185	CL[1]	O	1	Low

Table T. 208-Pin LQFP Numeric Pin Listing (Continued)

Pin No.	Signal	Type	Strength	Reset State
186	FRM	O	1	Low
187	M	O	1	Low
188	DD[3]	I/O	1	Low
189	DD[2]	I/O	1	Low
190	VSSIO	Pad Gnd		
191	DD[1]	I/O	1	Low
192	DD[0]	I/O	1	Low
193	nSDCS[1]	O	1	High
194	nSDCS[0]	O	1	High
195	SDQM[3]	I/O	2	Low
196	SDQM[2]	I/O	2	Low
197	VDDIO	Pad Pwr		
198	VSSIO	Pad Gnd		
199	SDCKE	I/O	2	Low
200	SDCLK	I/O	2	Low
201	nMWE/nSDWE	O	1	High
202	nMOE/nSDCAS	O	1	High
203	VSSIO	Pad Gnd		
204	nCS[0]	O	1	High
205	nCS[1]	O	1	High
206	nCS[2]	O	1	High
207	nCS[3]	O	1	High
208	nCS[4]	O	1	High

*With p/u' means with internal pull-up on the pin.

204-Ball TFBGA Package Characteristics

204-Ball TFBGA Package Specifications

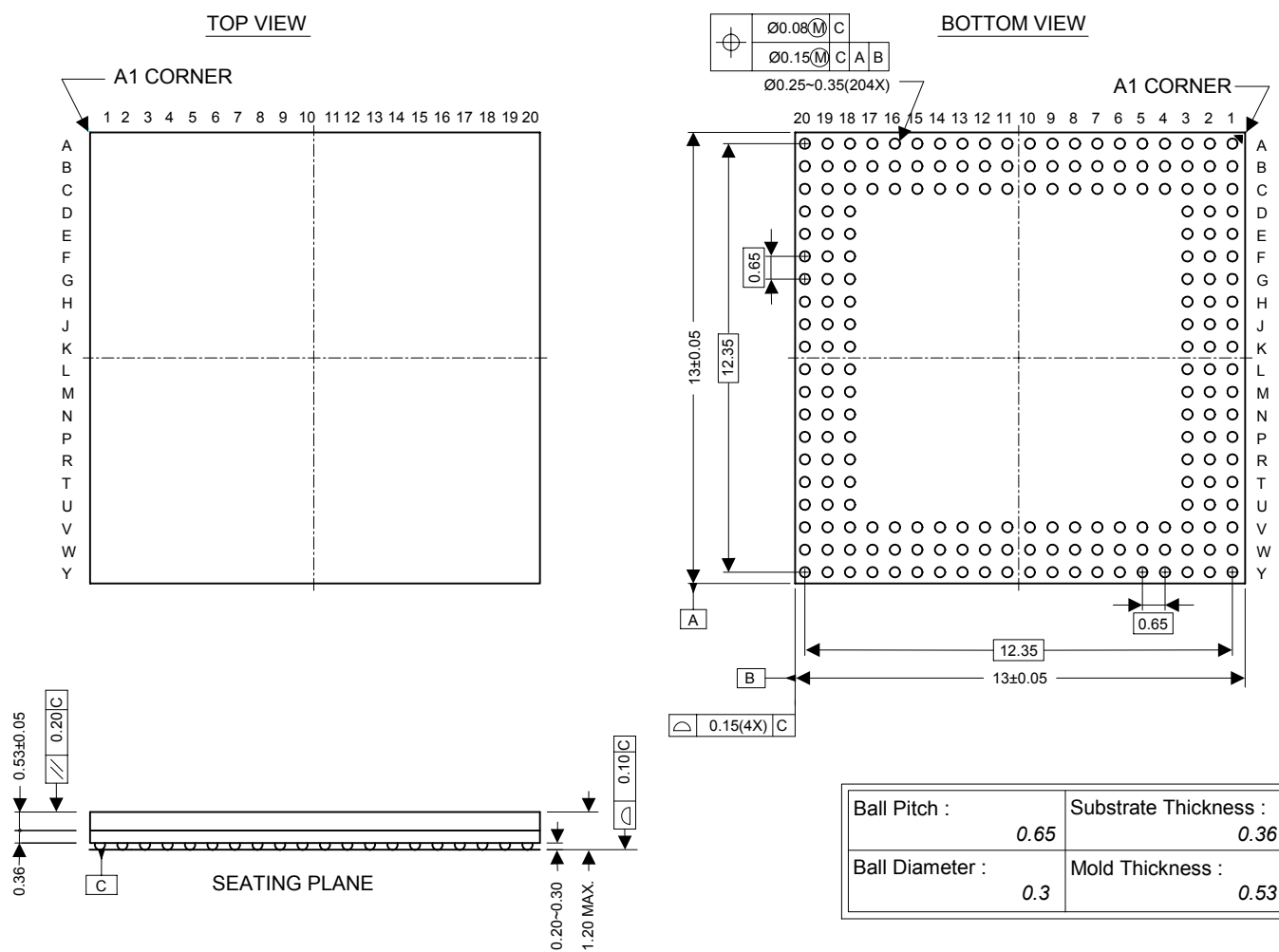


Figure 17. 204-Ball TFBGA Package

204-Ball TFBGA Ball Listing

The list is ordered by ball location.

Table 21. 204-Ball TFBGA Ball Listing

Ball Location	Name	Strength [†]	Reset State	Type	Description
A1	VDDIO			Pad power	Digital I/O power, 3.3 V
A2	EXPCLK	1		I	Expansion clock input
A3	nCS[3]	1	High	O	Chip select 3
A4	nCS[1]	1	High	O	Chip select 1
A5	nMWE/nSDWE	1	High	O	ROM, expansion write enable/SDRAM write enable control signal
A6	SDQM[2]	2	Low	O	SDRAM byte lane mask
A7	nSDCS[1]	1	High	O	SDRAM chip select 2
A8	DD[2]	1	Low	O	LCD serial display data
A9	FRM	1	Low	O	LCD frame synchronization pulse
A10	CL[1]	1	Low	O	LCD line clock
A11	VSSCORE			Core ground	Core ground
A12	D[1]	1	Low	I/O	Data I/O
A13	A[2]	2	Low	O	System byte address
A14	D[4]	1	Low	I/O	Data I/O
A15	A[5]	1	Low	O	System byte address
A16	nPWRFL			I	Power fail sense input
A17	MOSCOUT			O	Main oscillator out
A18	VSSIO			Pad ground	I/O ground
A19	VSSIO			Pad ground	I/O ground
A20	VSSIO			Pad ground	I/O ground
B1	WORD	1	Low	O	Word access select output
B2	VDDIO			Pad power	Digital I/O power, 3.3 V
B3	nCS[5]	1	Low	O	Chip select 5
B4	nCS[2]	1	High	O	Chip select 2
B5	nMOE/nSDCAS	1	High	O	ROM, expansion OP enable/SDRAM CAS control signal
B6	SDCKE	2	Low	O	SDRAM clock enable output
B7	nSDCS[0]	1	High	O	SDRAM chip select 0

Table 21. 204-Ball TFBGA Ball Listing (Continued)

Ball Location	Name	Strength [†]	Reset State	Type	Description
N18	D[17]	1	Low	I/O	Data I/O
N19	D[19]	1	Low	I/O	Data I/O
N20	A[18]/DRA[9]	1	Low	O	System byte address / SDRAM address
P1	EINT[3]			I	External interrupt
P2	nEINT[2]			I	External interrupt input
P3	DCD			I	UART 1 data carrier detect
P18	D[18]	1	Low	I/O	Data I/O
P19	A[20]/DRA[7]	1	Low	O	System byte address / SDRAM address
P20	D[20]	1	Low	I/O	Data I/O
R1	nEXTFIQ			I	External fast interrupt input
R2	PE[2]/CLKSEL	1	Input [‡]	I/O	GPIO port E / clock input mode select
R3	nTEST[0]	With p/u*		I	Test mode select input
R18	A[19]/DRA[8]	1	Low	O	System byte address / SDRAM address
R19	D[22]	1	Low	I/O	Data I/O
R20	A[21]/DRA[6]	1	Low	O	System byte address / SDRAM address
T1	PE[1]/BOOTSEL[1]	1	Input [‡]	I/O	GPIO port E / boot mode select
T2	PE[0]/BOOTSEL[0]	1	Input [‡]	I/O	GPIO port E / boot mode select
T3	nEINT[1]			I	External interrupt input
T18	D[21]	1	Low	I/O	Data I/O
T19	D[23]	1	Low	I/O	Data I/O
T20	A[22]/DRA[5]	1	Low	O	System byte address / SDRAM address
U1	VSSRTC			RTC ground	Real time clock ground
U2	RTCOUT			O	Real time clock oscillator output
U3	RTCIN			I/O	Real time clock oscillator input
U18	HALFWORD	1	Low	O	Halfword access select output
U19	D[24]	1	Low	I/O	Data I/O
U20	A[23]/DRA[4]	1	Low	O	System byte address / SDRAM address
V1	VDDRTC			RTC power	Real time clock power, 2.5V

Table 21. 204-Ball TFBGA Ball Listing (Continued)

Ball Location	Name	Strength [†]	Reset State	Type	Description
V2	VSSIO			Pad ground	I/O ground
V3	VSSIO			Pad ground	I/O ground
V4	PD[7]/SDQM[1]	1	Low	I/O	GPIO port D / SDRAM byte lane mask
V5	PD[4]	1	Low	I/O	GPIO port D
V6	PD[2]	1	Low	I/O	GPIO port D
V7	SSICLK	1	Input [‡]	I/O	DAI/CODEC/SSI2 serial clock
V8	SSIRXDA			I/O	DAI/CODEC/SSI2 serial data input
V9	nADCCS	1	High	O	SSI1 ADC chip select
V10	VDDIO			Pad power	Digital I/O power, 3.3V
V11	ADCCLK	1	Low	O	SSI1 ADC serial clock
V12	COL[7]	1	High	O	Keyboard scanner column drive
V13	COL[4]	1	High	O	Keyboard scanner column drive
V14	TCLK			I	JTAG clock
V15	BUZ	1	Low	O	Buzzer drive output
V16	D[29]	1	Low	I/O	Data I/O
V17	A[26]/DRA[1]	2	Low	O	System byte address / SDRAM address
V18	VDDIO			Pad power	Digital I/O power, 3.3 V
V19	VDDIO			Pad power	Digital I/O power, 3.3 V
V20	A[24]/DRA[3]	1	Low	O	System byte address / SDRAM address
W1	VSSIO			Pad ground	I/O ground
W2	VSSIO			Pad ground	I/O ground
W3	VSSIO			Pad ground	I/O ground
W4	PD[6]/SDQM[0]	1	Low	I/O	GPIO port D / SDRAM byte lane mask
W5	TMS	with p/u*		I	JTAG mode select
W6	PD[1]	1	Low	I/O	GPIO port D
W7	SSITXFR	1	Low	I/O	DAI/CODEC/SSI2 frame sync
W8	SSIRXFR	1	Input [‡]	I/O	DAI/CODEC/SSI2 frame sync
W9	VSSCORE			Core Ground	Core Ground
W10	DRIVE[1]	2	High / Low	I/O	PWM drive output

Table 21. 204-Ball TFBGA Ball Listing (Continued)

Ball Location	Name	Strength [†]	Reset State	Type	Description
W11	ADCOUT	1	Low	O	SSI1 ADC serial data output
W12	FB[0]			I	PWM feedback input
W13	COL[5]	1	High	O	Keyboard scanner column drive
W14	COL[2]	1	High	O	Keyboard scanner column drive
W15	COL[0]	1	High	O	Keyboard scanner column drive
W16	D[30]	1	Low	I/O	Data I/O
W17	A[27]/DRA[0]	2	Low	O	System byte address / SDRAM address
W18	D[26]	1	Low	I/O	Data I/O
W19	VDDIO			Pad power	Digital I/O power, 3.3V
W20	D[25]	1	Low	I/O	Data I/O
Y1	VSSIO			Pad ground	I/O ground
Y2	VSSIO			Pad ground	I/O ground
Y3	VSSIO			Pad ground	I/O ground
Y4	PD[5]	1	Low	I/O	GPIO port D
Y5	PD[3]	1	Low	I/O	GPIO port D
Y6	PD[0]/LEDFLSH	1	Low	I/O	GPIO port D / LED blinker output
Y7	SSITXDA	1	Low	O	DAI/CODEC/SSI2 serial data output
Y8	ADCIN			I	SSI1 ADC serial input
Y9	VDDCORE			Core power	Digital core power, 2.5V
Y10	DRIVE[0]	2	Input [‡]	I/O	PWM drive output
Y11	SMPCLK	1	Low	O	SSI1 ADC sample clock
Y12	FB[1]			I	PWM feedback input
Y13	COL[6]	1	High	O	Keyboard scanner column drive
Y14	COL[3]	1	High	O	Keyboard scanner column drive
Y15	COL[1]	1	High	O	Keyboard scanner column drive
Y16	D[31]	1	Low	I/O	Data I/O
Y17	D[28]	1	Low	I/O	Data I/O
Y18	D[27]	1	Low	I/O	Data I/O
Y19	A[25]/DRA[2]	2	Low	O	System byte address / SDRAM address

Table W. JTAG Boundary Scan Signal Ordering (Continued)

LQFP Pin No.	TFBGA Ball	PBGA Ball	Signal	Type	Position
148	H18	G11	A[7]	O	274
150	F20	D15	D[7]	I/O	276
151	G19	F13	nBATCHG	I	279
152	E20	C16	nEXTPWR	I	280
153	F19	F12	BATOK	I	281
154	G18	C15	nPOR	I	282
155	D20	E13	nMEDCHG/nBROM	I	283
156	F18	B16	nURESET	I	284
161	D19	B14	WAKEUP	I	285
162	E19	D11	nPWRFL	I	286
163	C19	A13	A[6]	O	287
164	C20	F10	D[6]	I/O	289
165	E18	B13	A[5]	O	292
166	B20	E10	D[5]	I/O	294
169	B16	B12	A[4]	O	297
170	A16	D10	D[4]	I/O	299
171	C15	A11	A[3]	O	302
172	B15	G9	D[3]	I/O	304
173	A15	B11	A[2]	O	307
175	C14	A10	D[2]	I/O	309
176	B14	F9	A[1]	O	312
177	A14	B10	D[1]	I/O	314
178	C13	E9	A[0]	O	317
179	B13	A9	D[0]	I/O	319
184	A13	D8	CL2	O	322
185	C12	B8	CL1	O	324
186	B12	E8	FRM	O	326
187	A12	A7	M	O	328
188	C11	F8	DD[3]	I/O	330
189	B11	B7	DD[2]	I/O	333
191	B10	A6	DD[1]	I/O	336
192	A10	G8	DD[0]	I/O	339
193	A9	B6	nSDCS[1]	O	342
194	B9	D7	nSDCS[0]	O	344
195	C9	A5	SDQM[3]	I/O	346
196	A8	E7	SDQM[2]	I/O	349
199	B8	F7	SDCKE	I/O	352
200	C8	A4	SDCLK	I/O	355

